


INFORMATION DISCLOSURE STATEMENT PTO-1449	Atty. Docket No. 971003B	Serial No. Not yet assigned
	Applicants: Hideki MATSUMURA et al.	
	Filing Date: January 10, 2002	Group Art Unit: 1763 (Expected)

U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
MD	AA	3,652,331	Yamazaki	3/1972	117	201
MB	AB	4,237,150	Wiesmann	12/1980	427	74
MS	AC	5,160,544	Garg et al.	11/1992	118	724
MD	AD	5,366,919	Tanaka et al.	11/1994	437	52
MD	AE	5,397,737	Mahan et al.	3/1995	437	101
MS	AF	5,795,828	Endo et al.	8/1996	438	678
MD	AG	5,840,600	Yamazaki et al.	11/1998	438	151
MS	AH	5,149,375	Matsuyama	9/1992	118	719
MD	AI	5,693,173	Colombo et al.	12/1997	156	345
MD	AJ	5,183,529	Potter et al.	2/1993	156	613
MS	AK	5,186,973	Garg et al.	2/1993	427	590
MD	AL	5,209,812	Wu et al.	5/1993	156	613
MD	AM	5,591,484	Poncelet et al.	1/1997	427	249
MD	AN	5,054,421	Ito et al.	10/1991	118	723
MD	AO	5,186,973	Garg et al.	10/1991	427	590
MD	AP	6,069,094	Matsumura et al.	5/2000	438	788

FOREIGN PATENT DOCUMENTS

Document No.		Date	Country	Translation (Yes or No)
	AQ 63-40314	2/1988	Japan	No

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OTHER DOCUMENTS

<u>and</u>	AR	S. Yamazaki et al. SILICON NITRIDE PRERARED BY THE $\text{SiH}_4\text{-NH}_3$ REACTION WITH CATALYSIS, Japan Journal of Applied Physics, vol. 9, No. 12, dec. 1970, pp.1467-1477
<u>and</u>	AS	
Examiner <u>M. H. H. H.</u> Date Considered <u>11-25-03</u>		